



# Understanding grain boundary segregation under irradiation: A mesoscale modeling study

October 2023

*Changing the World's Energy Future*

Sourabh Bhagwan Kadambi, Jia-Hong Ke, Boopathy Kombaiah, Mukesh Bachhav



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**October 2023**

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**<http://www.inl.gov>**

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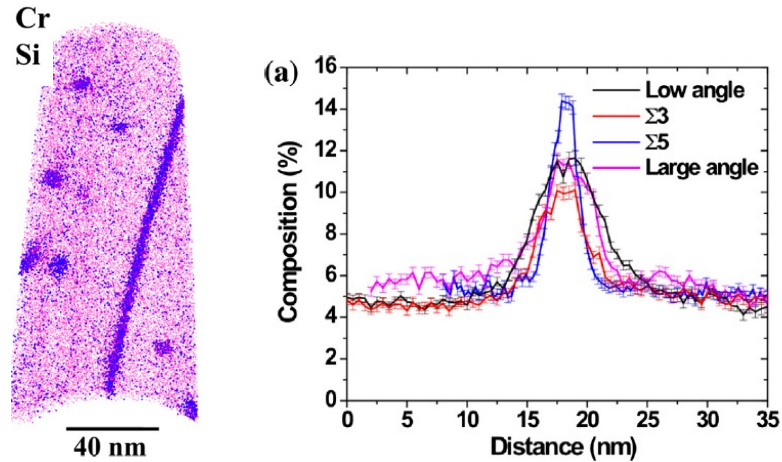
# Understanding grain boundary segregation under irradiation: A mesoscale modeling study

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Nuclear Science & Technology  
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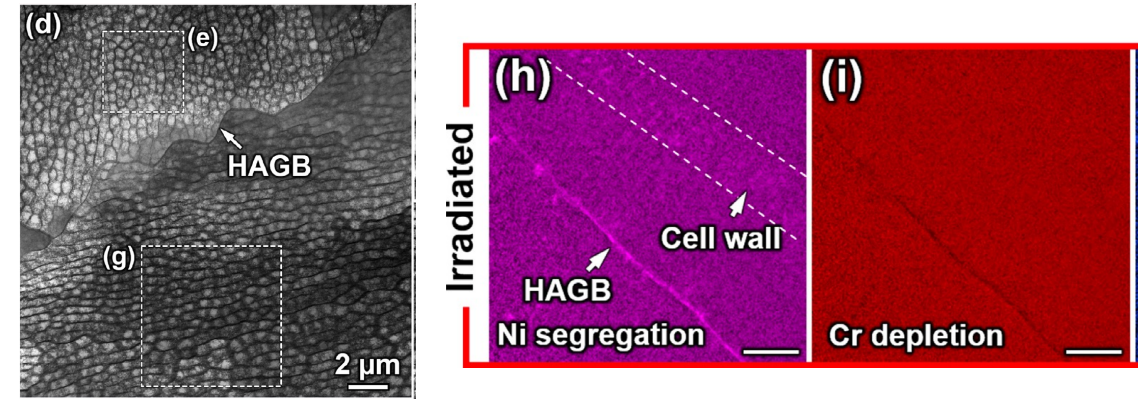
# Radiation-induced segregation in steels

Cr enrichment in Fe-6Cr (at.%) at low T [1]



APT profile of neutron irradiated Fe-6at.% Cr (1.82 dpa, 290 C)

RIS in additively manufactured 316L SS [2]



TEM/ HAADF STEM images of 3.5 MeV  $\text{Fe}^{++}$  irradiated AM 316LN SS ( $3 \times 10^{-3}$  dpa/s, 450 C)

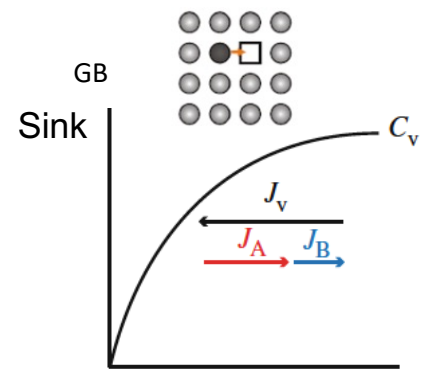
- Complex dependence on temperature, irradiation conditions and material/ microstructural features
- *Required modeling capability: multicomponent kinetics, non-ideal GB sink, RIS at dislocation cell walls*

[1] Bachhav et al., J. Nucl. Mater. 453 (2014) 334 – 339

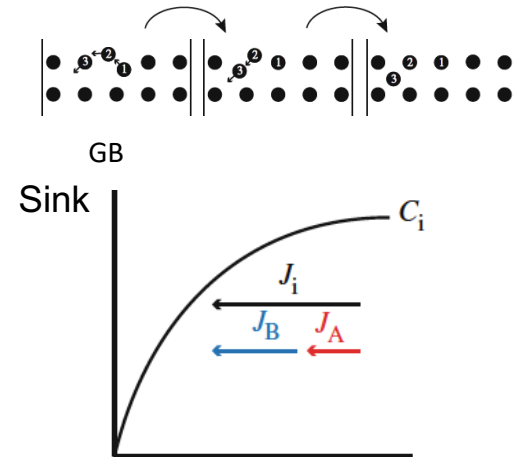
[2] Z. Shang, Journal of Nuclear Materials 546 (2021) 152745

# Radiation induced segregation (RIS): theory

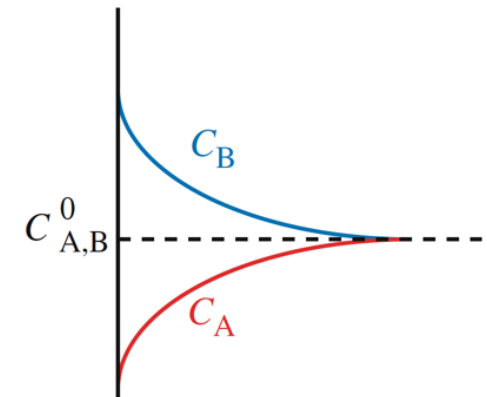
## Atom-vacancy exchange mechanism



## Self-interstitial dumbbell mechanism



## Atomic redistribution



Enrichment/ depletion of atoms due to difference in diffusivities

[1] Was, G. S. Fundamentals of Radiation Materials Science, Springer (2016)

[2] Ardell and Bellon, Curr. Opin. Solid State Mater Sci. 20(3) (2016) 115

# Radiation induced segregation (RIS): theory

## Fluxes for atoms A, B, C...

$$J_A^V = -L_{AA}^V \nabla(\mu_A - \mu_V) - L_{AB}^V \nabla(\mu_B - \mu_V) - \dots$$

$$J_A^I = -L_{AA}^I \nabla(\mu_A + \mu_I) - L_{AB}^I \nabla(\mu_B + \mu_I) - \dots$$

$$J_A = J_A^V + J_A^I$$

$$J_A + J_B + J_C = 0$$

## Total fluxes (reduced form B, C...)

$$J_B = -\tilde{L}_{BB} \nabla \tilde{\mu}_B - \tilde{L}_{BC} \nabla \tilde{\mu}_C \dots - L_{BV} \nabla \mu_V - L_{BI} \nabla \mu_I \quad (\text{atoms})$$

$$J_V = -\tilde{L}_{vB} \nabla \tilde{\mu}_B - \tilde{L}_{vC} \nabla \tilde{\mu}_C \dots - L_{vV} \nabla \mu_V \quad (\text{defects})$$

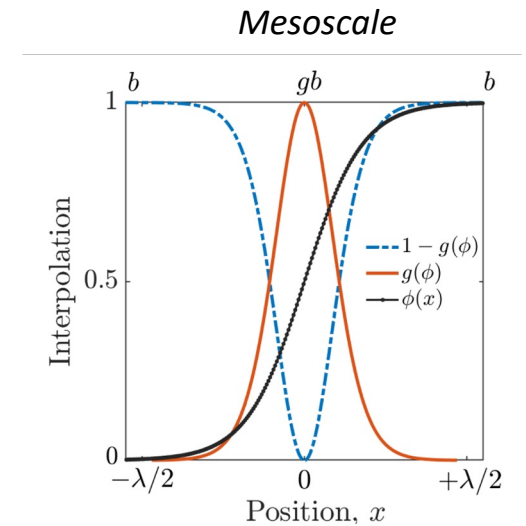
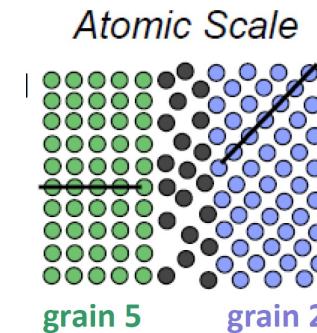
$$J_V = J_I$$

# Phase-field modeling of RIS

Chemical potential-based diffusion, rate theory

$$\begin{aligned}
 \text{(atoms)} \quad & \chi_B \frac{\partial \tilde{\mu}_B}{\partial t} + \chi_{BC} \frac{\partial \tilde{\mu}_C}{\partial t} + \dots = -\nabla \cdot J_B \\
 \text{(defects)} \quad & \chi_{vv} \frac{\partial \mu_v}{\partial t} = -\nabla \cdot J_v + \underbrace{\dot{P}_v}_{\text{Production}} - \underbrace{\dot{R}_{VI} c_v c_I}_{\text{Recombination}} - \underbrace{\dot{S}_v(\eta) c_v}_{\text{Sink}}
 \end{aligned}$$

- Full thermodynamic & kinetic coupling
- Model alloys: FCC FeCrNi, BCC FeCr
- MOOSE: open-source, finite element, C++



[1] Kadambi, S. B., Schwen, D., Zhang, Y. & He, L.. Phase-field Modeling of Radiation Induced Segregation in Multicomponent Alloys: Kinetic Monte Carlo and CALPHAD Informed Simulations. *Under Preparation*.

[2] MOOSE workshop, PhaseField, INL



# Application to additively manufactured FCC Fe-Cr-Ni

Sourabh Kadambi, Lingfeng He<sup>[1]</sup>, Andrea Jokisaari

[1] North Carolina State University

Funded by AMMT and INL's LDRD program

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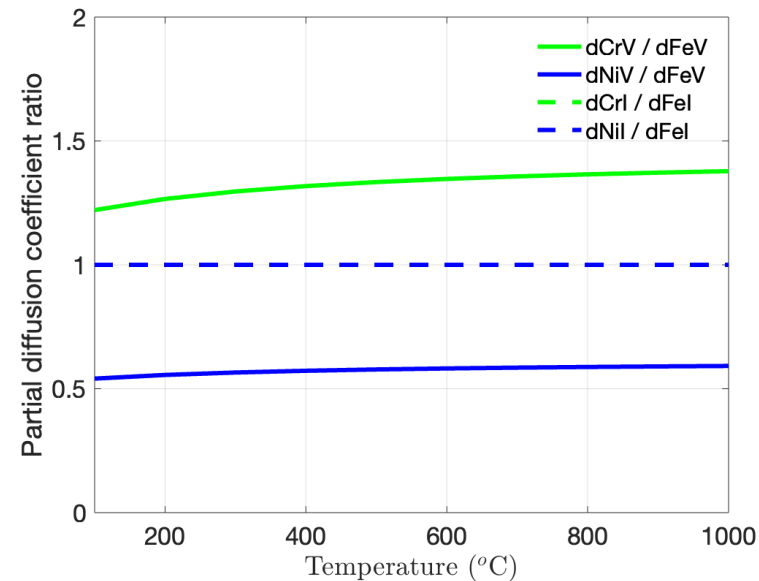
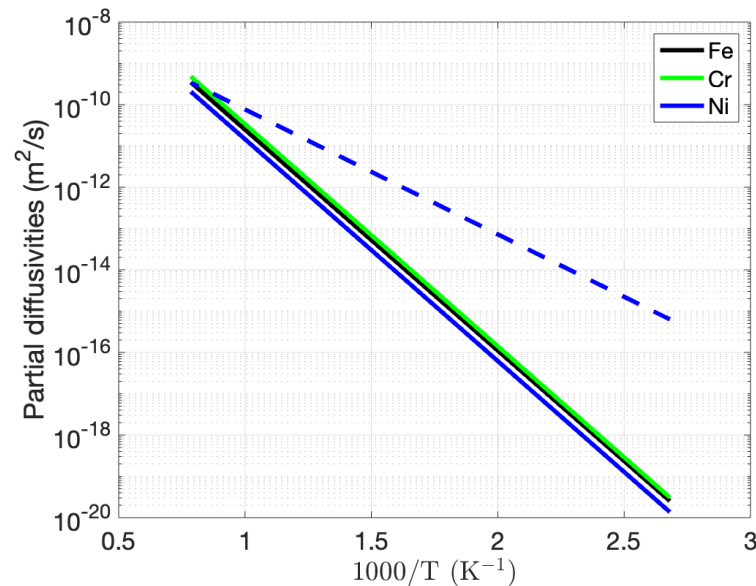
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# Model parameterization for FCC FeCrNi

- Vacancy transport: CALPHAD-type assessment from experimental tracer diffusivity data [1]
- SIA diffusivity (difficult to compute): (i) **assumed equal** [2], (ii) binding energies from atomistic calculation

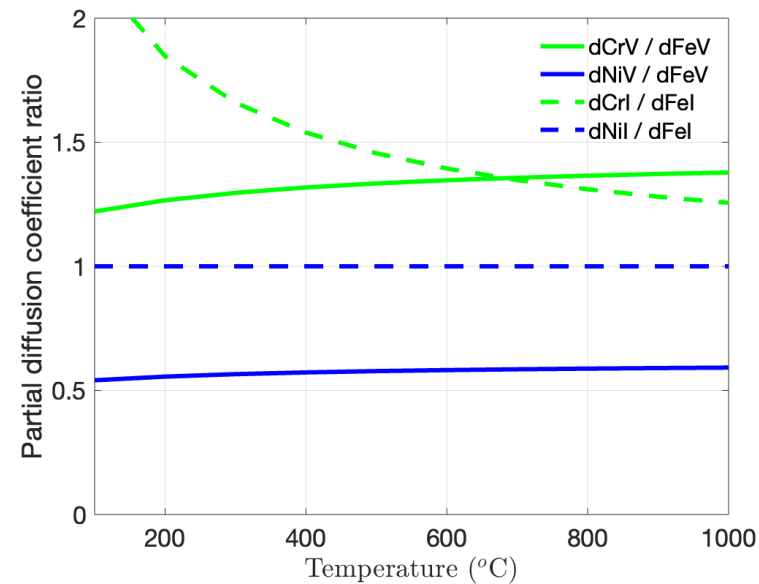
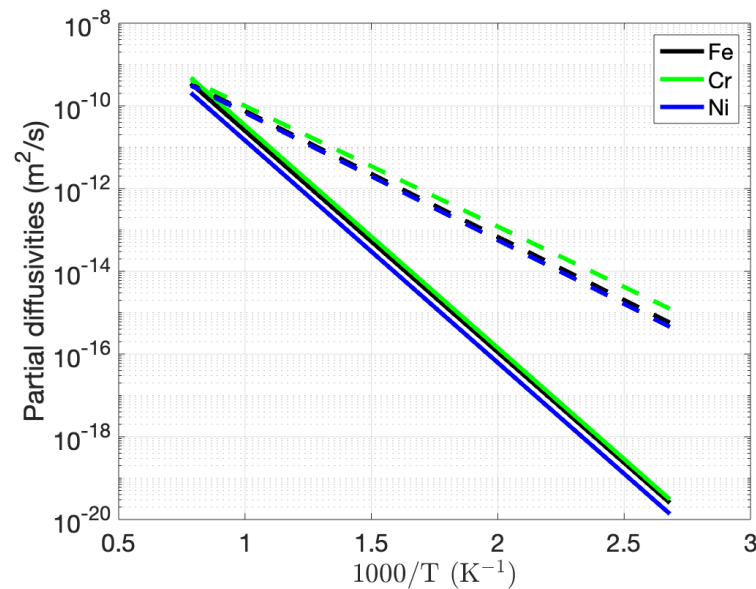


[1] Yang et al., J. Nucl. Mater. 473 (2016) 35 – 53

[2] Allen et al., J. Nucl. Mater. 255 (1998) 44 – 58 (MIK model)

# Model parameterization for FCC FeCrNi

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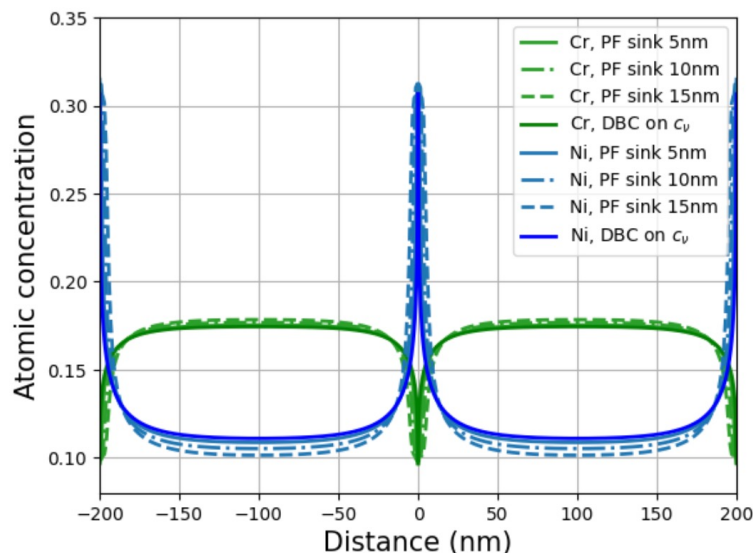


[1] Yang et al., J. Nucl. Mater. 473 (2016) 35 – 53

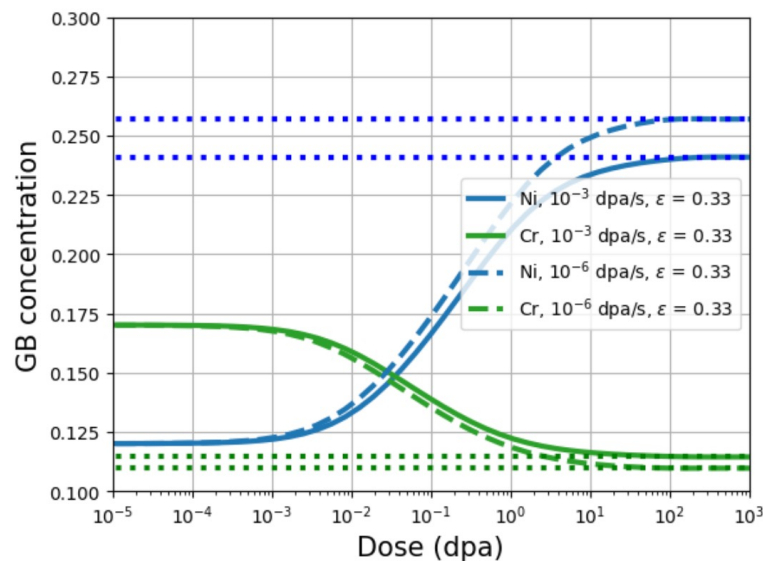
[2] Allen et al., J. Nucl. Mater. 255 (1998) 44 – 58 (MIK model)

# Results: effect of grain boundary sink strength

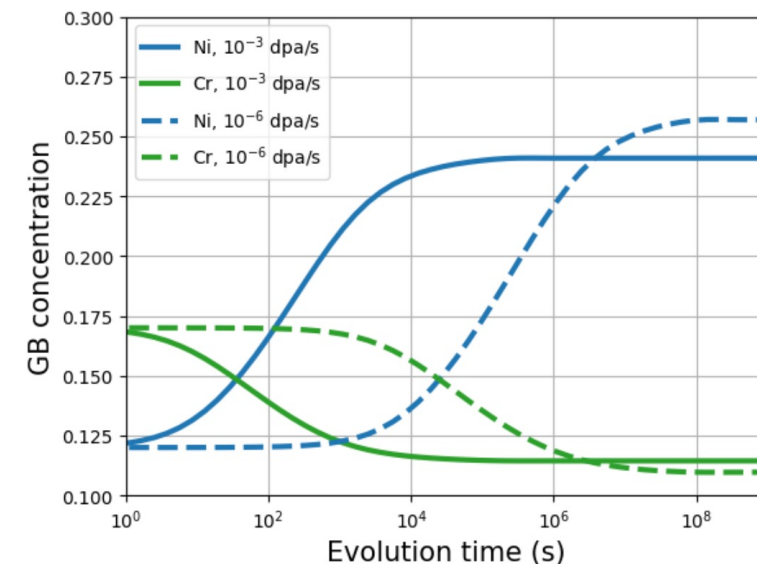
*RIS in Fe-17Cr-12Ni (at.%)*



*RIS vs. radiation damage*



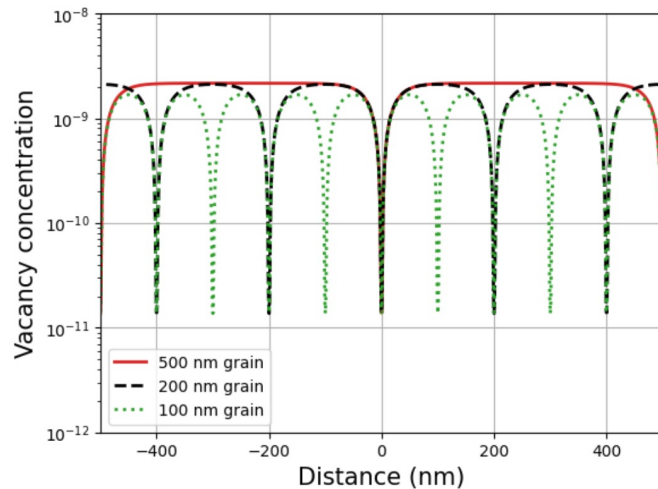
*Dose rate dependence*



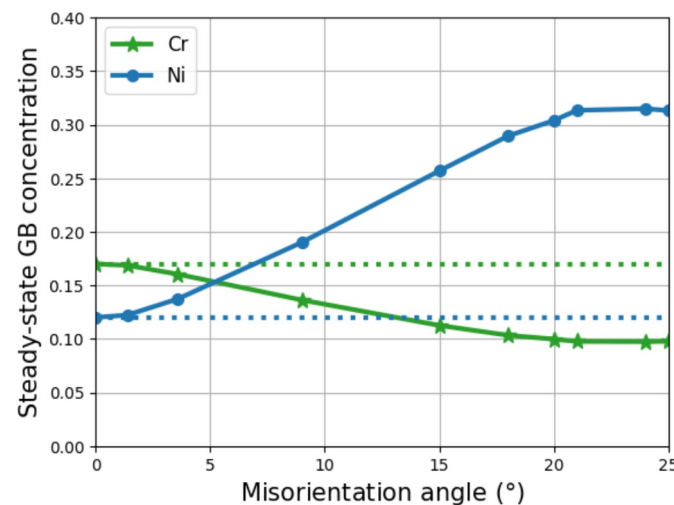
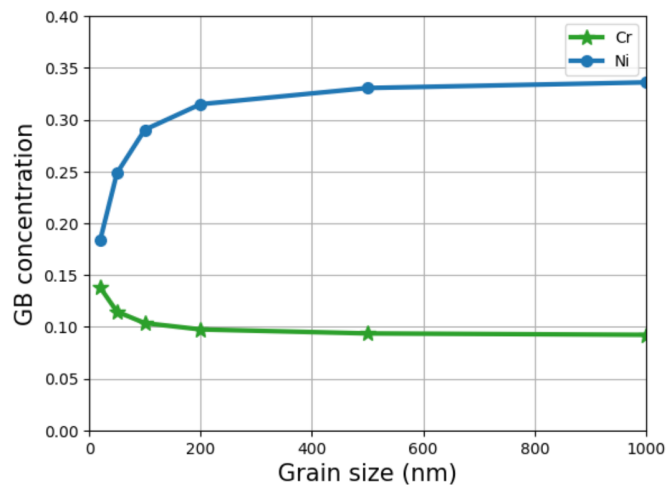
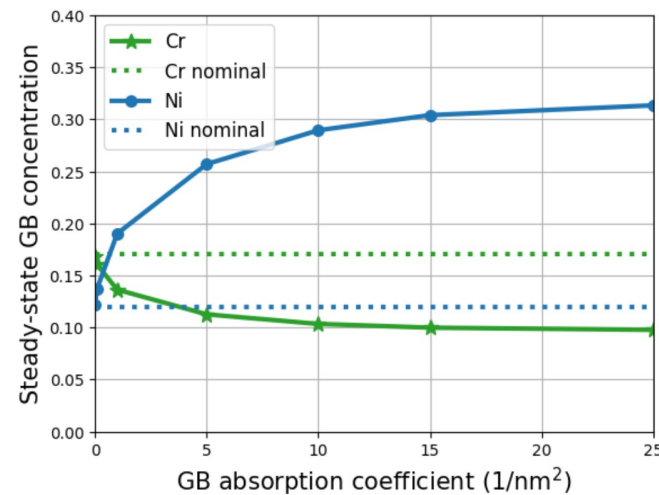
RIS from Dirichlet BC/ sharp interface is compared against sink absorption rate across diffuse phase-field sink for ideal HAGB

# Results: effect of grain boundary sink strength

Grain size dependence



GB structure dependence [1]

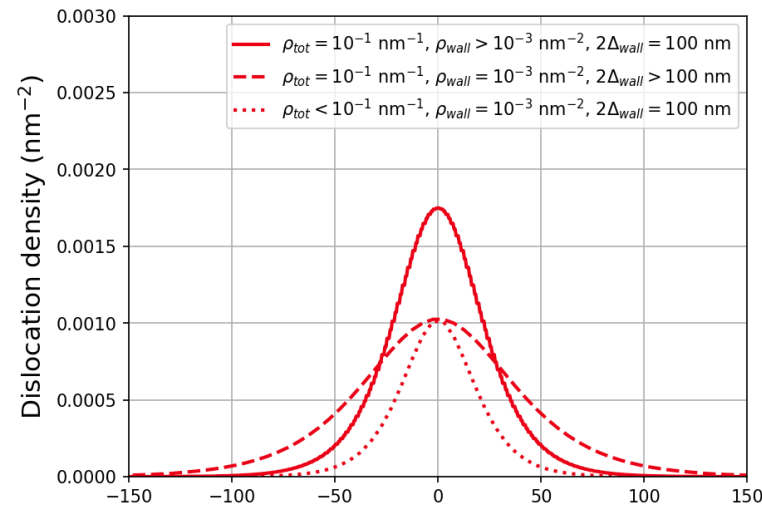
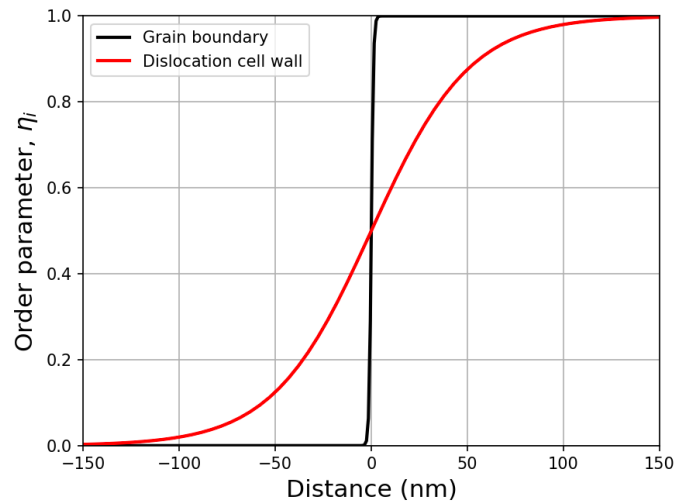


Dimensional sink strength of ideal GB is above  $25 \text{ nm}^{-2}$  for misorientation above  $21^\circ$

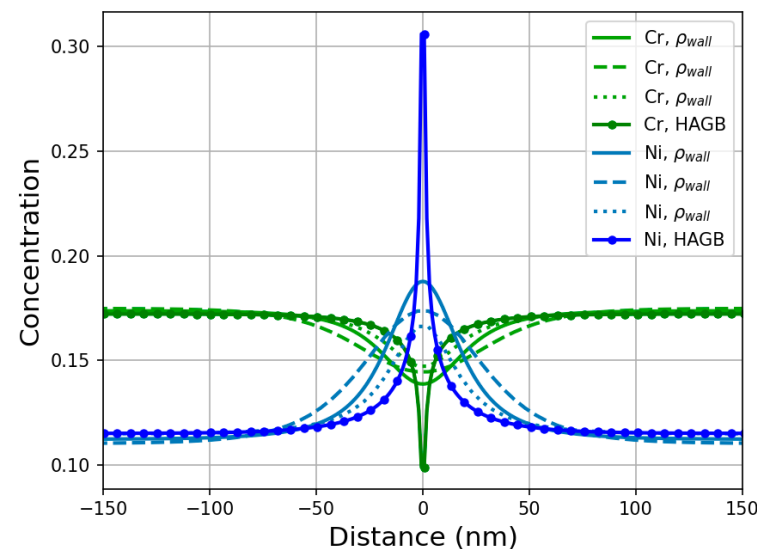
# RIS in AM microstructure: dislocation cell walls



*Diffuse interface description*



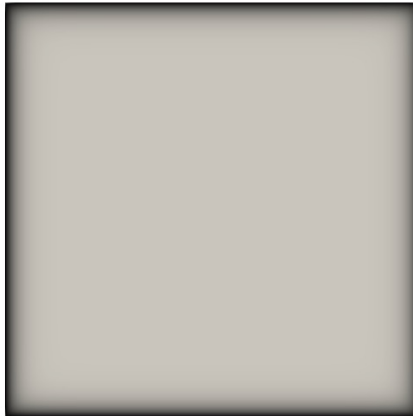
Sink absorption rate are a function of dislocation density (time/ damage dependent)



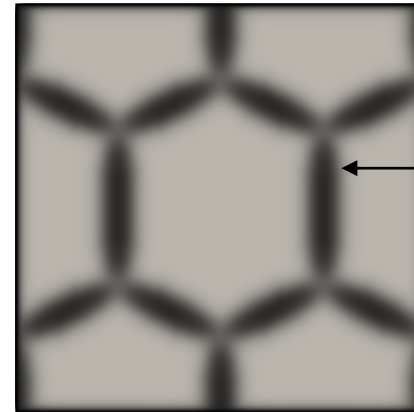
Dimensional sink strength of  $0.025 \text{ nm}^{-2}$  was used for dislocation density of  $10^{-3} \text{ nm}^{-2}$

# RIS in AM microstructure: 2D simulation

Reference grain

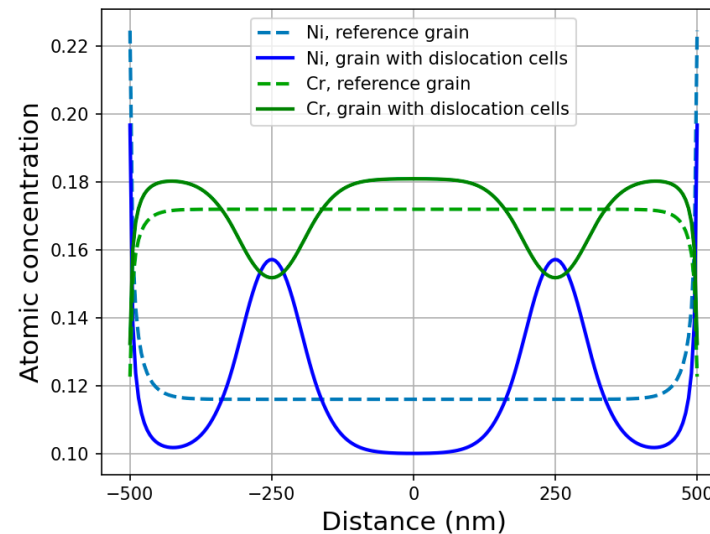
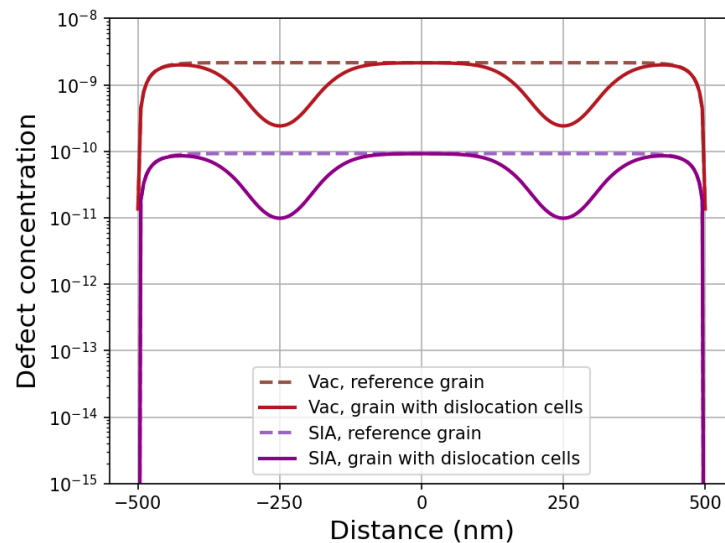


AM microstructure



Dislocation cell wall

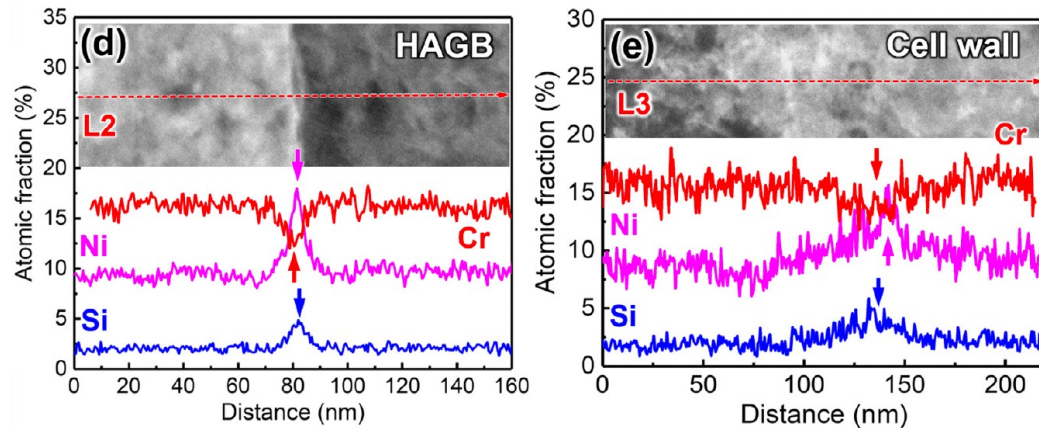
HAGB



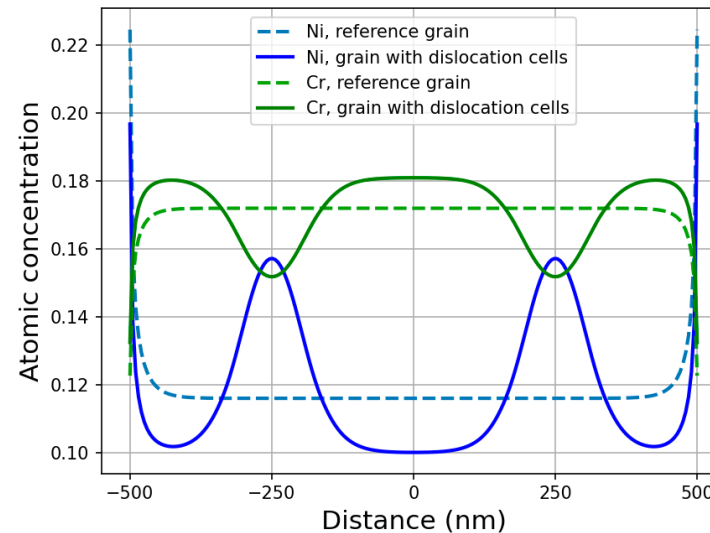
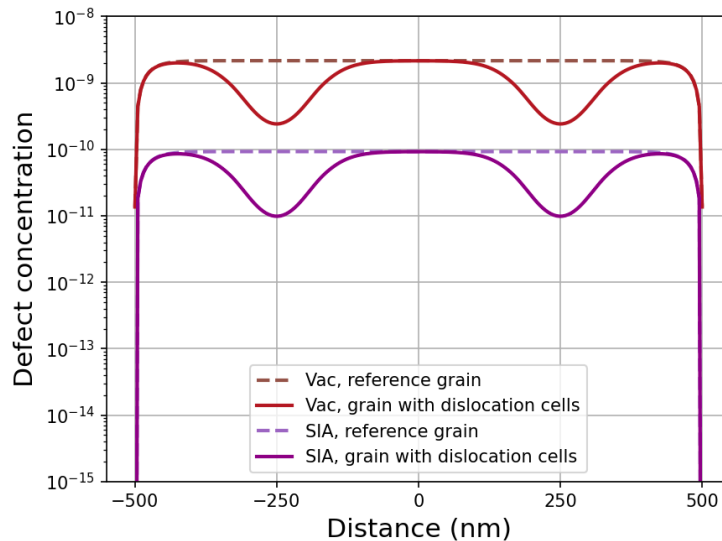
- Lower RIS at HAGB in AM grain due to network dislocations acting as additional sinks
- Demonstrates effect of microstructural features on fluxes reaching GB



# RIS in AM microstructure: 2D simulation



Z. Shang, C. Fan, J. Ding et al., Journal of Nuclear Materials 546 (2021) 152745



- Lower RIS at HAGB in AM grain due to network dislocations acting as additional sinks
- Demonstrates effect of microstructural features on fluxes reaching GB



# Application to BCC Fe-Cr alloy

Sourabh Kadambi, Jia-Hong Ke, Boopathy Kombaiah, Mukesh Bachhav

Funded by INL's LDRD program

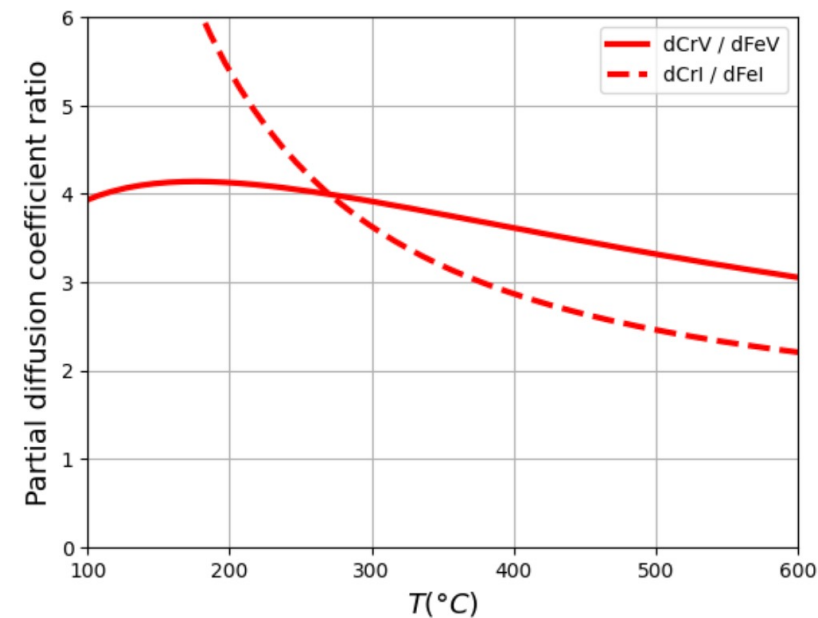
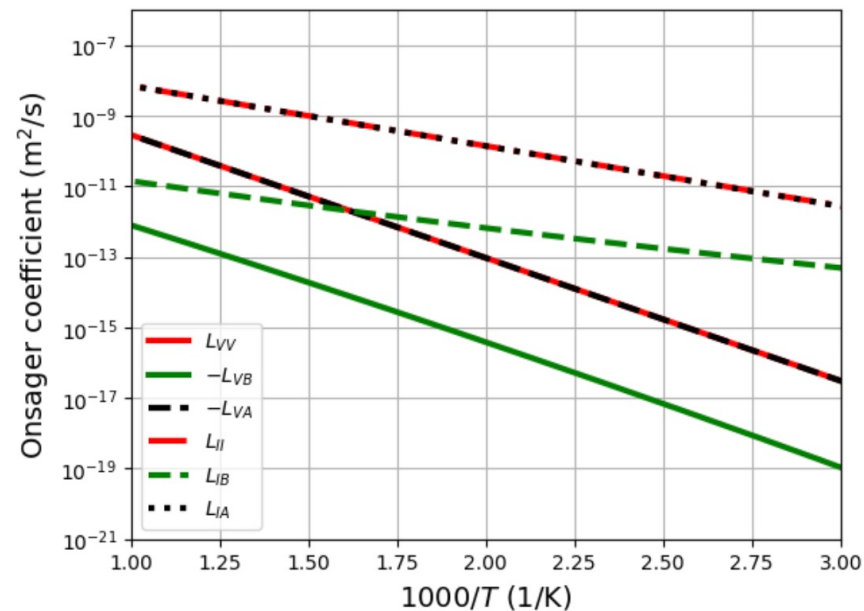
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**INL** Idaho National Laboratory

# Model parameterization for BCC FeCr

*DFT data [1] is provided as input to Kinetic Cluster Expansion (KineCluE) [2] model to compute dilute limit Onsager transport coefficients*

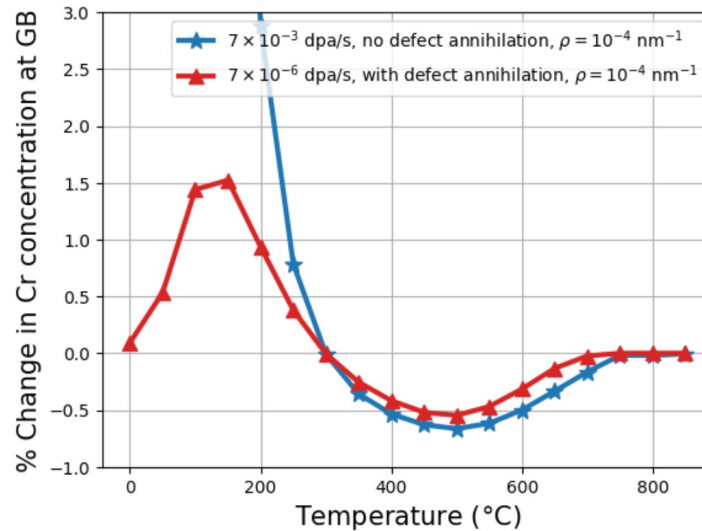


[1] T. Schuler, et al., Computational Materials Science 172 (2020) 109191

[2] L. Messina, et al., Physical Review B 90, 104203 (2014)

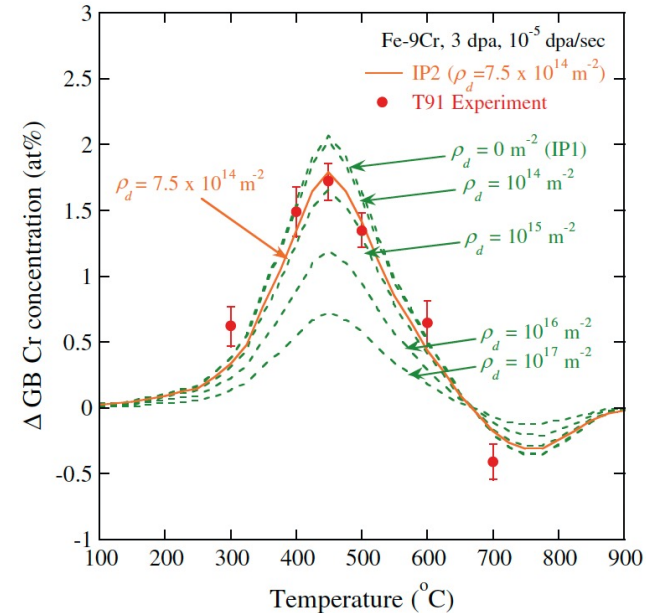
# RIS in BCC FeCr: cross-over in segregation

Phase-field prediction using KineCluE model for Fe-0.1Cr (at.%)



Need to extend capability to Fe-9Cr  
and determine physically relevant  
recombination rates

Fe-9Cr (at.%), Wharry-Was (2014)



Described bell-shape as resulting from  
temperature dependent diffusivity,  
recombination effects

[1] J.P. Wharry, G.S. Was, Acta Materialia 65 (2014) 42–55

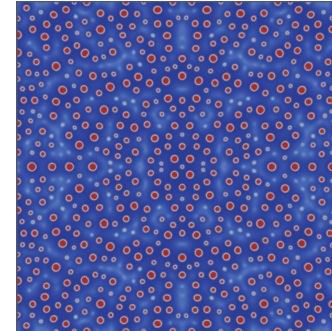
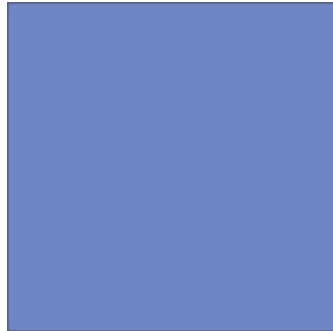
[2] L. D. Xia et al., Nuclear Engineering and Technology 52 (2020) 148 – 154

# Spinodal decomposition under irradiation

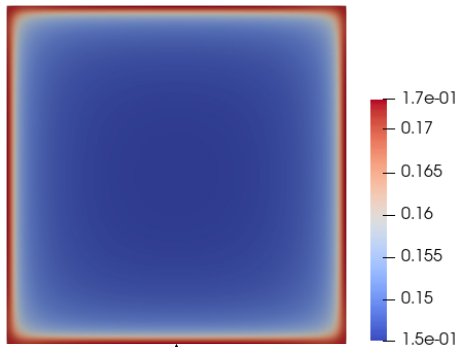
Nominal concentration < critical spinodal

Nominal concentration > critical spinodal

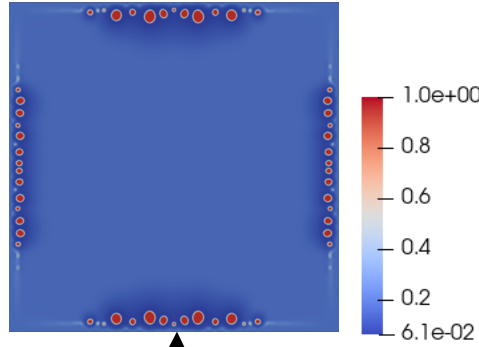
Thermal,  
bulk



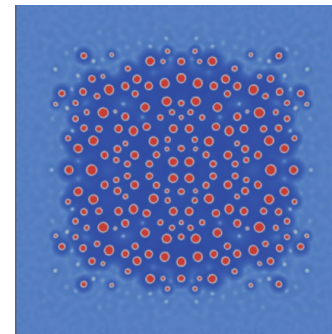
Irradiation,  
GB sink



RIS near GB



Spinodal decomposition due  
to RIS



Denuded zone

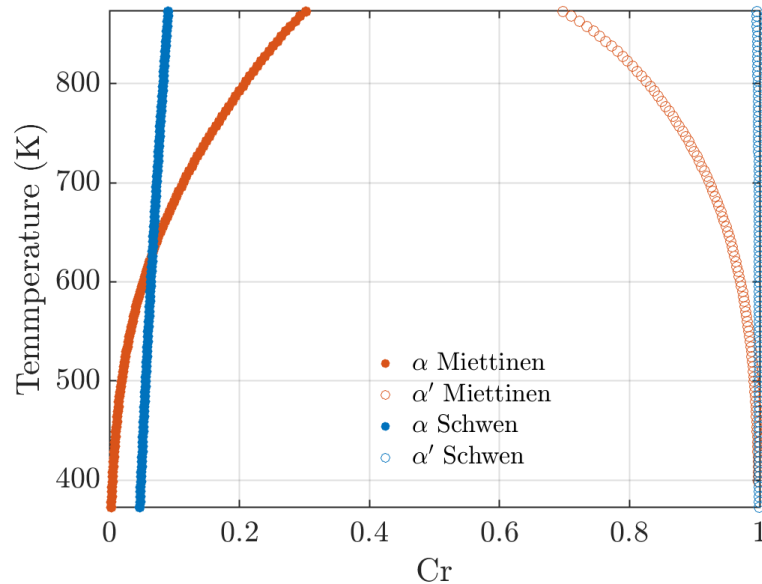
- Accelerated kinetics within grain due to higher point defect concentrations under irradiation
- Slow kinetics near GB due to GB sink effect reducing point defect concentration

[1] J.P. Wharry, G.S. Was, Acta Materialia 65 (2014) 42–55

[2] L. D. Xia et al., Nuclear Engineering and Technology 52 (2020) 148 – 154

# Nucleation under irradiation

(Red) Equilibrium  $\alpha - \alpha'$  phase boundary using Calphad free energy



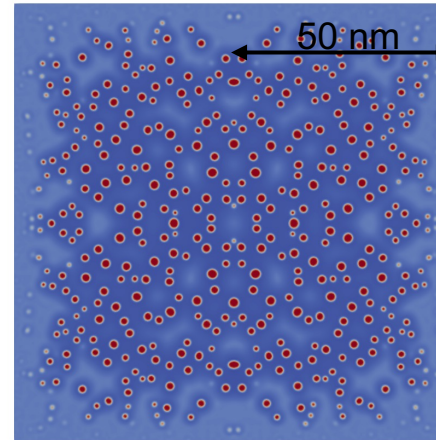
Critical nucleation barrier:

$$\Delta G_{nucl}^* = f_{eq}^{\alpha'} - f - (c_{eq}^{\alpha'} - c) \tilde{\mu}$$

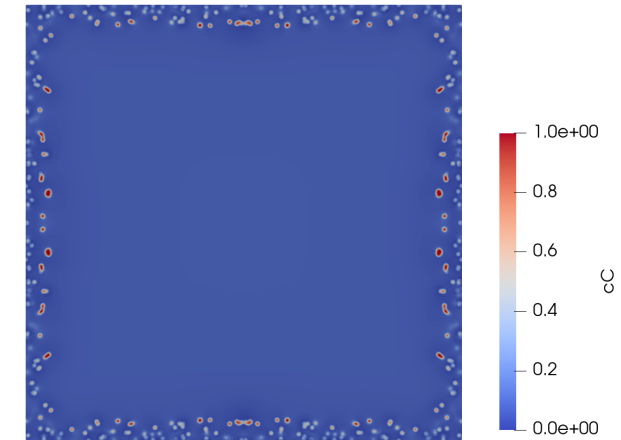
Classical nucleation rate:

$$\tilde{J}^* = \tilde{k}_1 \left( \frac{D_{Cr}}{\Delta G_{nucl}^* n} \right) \exp \left( - \frac{k_2}{\Delta G_{nucl}^*} \right)$$

Nominal Cr concentration  
> solvus



Nominal Cr concentration  
= solvus



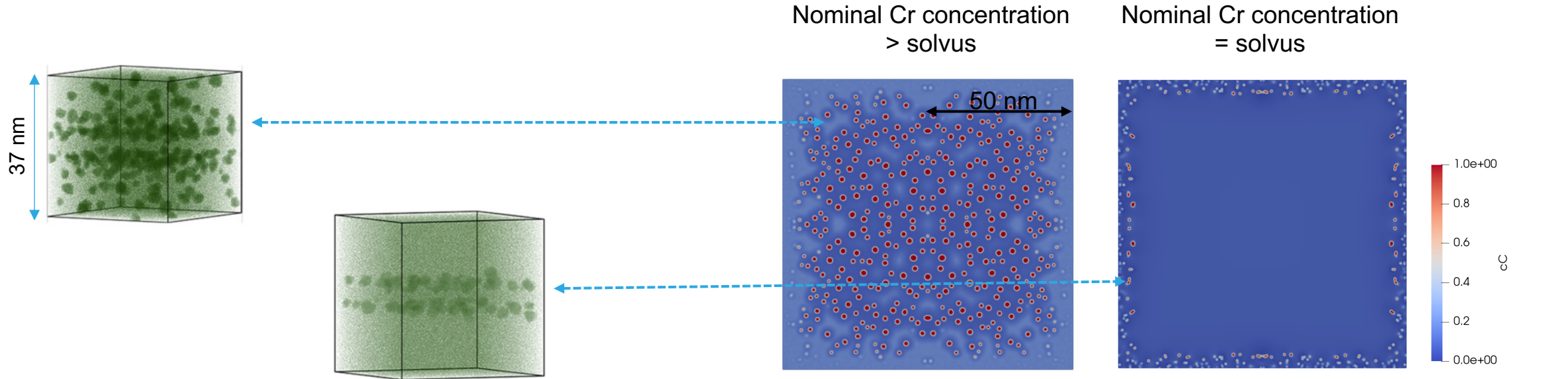
- High nucleation probability and kinetics (Cr mobility) due to excess point defect concentration
- Ballistic mixing is expected to alter  $\alpha - \alpha'$  phase boundary/ stability

- RIS at GB increases Cr concentration above solubility limit
- Slow nucleation rate and growth kinetics due to low point defect concentration near GB

[1] Miettinen, Calphad 15(4) (1991) 317—425

[2] D. Schwen, et al., Journal of Nucl. Mater. 439 (2013) 180—184

# Nucleation under irradiation



Phase-field predictions are consistent with Atomistic KMC simulations at 290 C [1,2]

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- Ballistic mixing is expected to alter  $\alpha - \alpha'$  phase boundary/ stability
- RIS at GB increases Cr concentration above solubility limit
- Slow nucleation rate and growth kinetics due to low point defect concentration near GB

[1] F. Soisson and T. Jourdan, Acta Materialia 103 (2016) 870—881

[2] E. Martinez, et al., Physical Review Letters 120 (2018) 106101



# Conclusions

## *AM microstructures representative of 316 SS*

- Parameterized using experimental + atomistic data + parameter tuning
- Dislocation density-based sink was employed for static cell walls
- In comparing RIS at dislocation cell walls and HAGB, simulations predict lower peak concentrations

## *Microstructure evolution in ferritic FeCr alloy*

- RIS model predicts cross-over of Cr from depletion at high T to enrichment at low T
- Spatially-resolved simulations demonstrate RIS and  $\alpha'$  precipitation simultaneously
- Current limitation: dilute Cr concentration in the calculation of Onsager transport coefficients